Dielectric characteristics

Class I Dielectrics

Multilayer Ceramic Capacitors are generally divided into classes which are defined by the capacitance temperature characteristics over specified temperature ranges. These are designated by alpha numeric codes. Code definitions are summarised below and are also available in the relevant national and international specifications.

Capacitors within this class have a dielectric constant range from 10 to 100. They are used in applications which require ultra stable

dielectric characteristics with negligible dependence of capacitance and dissipation factor with time, voltage and frequency. They exhibit the following characteristics:-

- a) Time does not significantly affect capacitance and dissipation factor (Tan δ) no ageing.
- b) Capacitance and dissipation factor are not affected by voltage.
- c) Linear temperature coefficient.

		Class I Dielectrics													
		COG/NPO (Porcelain)	P90 (Porcelain)	C0G/	NP0	X8G	Class I High Temperature								
		Ultra stable	Ultra stable	Ultra s	stable	Ultra stable	Ultra stable								
Dielectric	IECQ-CECC	-	-	1B/	CG	-	-	-							
classifications	EIA	COG/NP0	P90	C0G/	NP0	X8G	-	-							
	MIL	-	-	CG (BP)	-	-	-							
Ordering code	DLI	CF	AH	-	-	-	-	-							
	Novacap	-	-	-	N	-	F	D, RD							
Ordering code	Syfer	-	-	Q, U	С	Н	-	G							
	Voltronics	F	Н	Q	-	-	-	-							
Rated temperature range		-55°C to +125°C	-55°C to +125°C	-55°C to +125°C	-55°C to +125°C	-55°C to +150°C	-55°C to +160°C	-55°C to +200°C							
Maximum capacitance	No DC voltage applied	0 ± 15 ppm/°C	± 20 ppm/°C	0 ± 30 ppm/°C	± 30 ppm/°C	0 ± 30 ppm/°C	0 ± 30 ppm/°C	0 ± 30 ppm/°C							
change over temperature range	Rated DC voltage applied				-										
Tangent of loss angle (tan δ)		≤0.	.05	≤0.0005 @1MHz	>50pF ≤50pF 0.00	≤0.0015 15 (<u>15</u> + 0.7) Cr	≤0.001								
Insulation resistance (Ri)	Time constant (Ri x Cr)	@25°C = 1 @125°C = 1		(wl	100GΩ or 1000 s nichever is the lea	st)	@25°C = 100 GΩ or 100 ΩF @ 160 °C & 200 °C = 1 GΩ or 10 ΩF (whichever is the least)								
	Cr <4.7pF	±0.05pF, ±0.10pF, ±0.25pF, ±0.5pF													
Capacitance Tolerance	Cr ≥4.7 to <10pF	±0.10pF, ±0.25pF, ±0.5pF													
	Cr ≥10pF	±1%, ±2%, ±5%, ±10%													
Dielectric	<u>≤</u> 200V			2.5 ti	mes		2.5 times								
strength Voltage applied	>200V to <500V		2.5 times	Rated volta	ge + 250V		Rated voltage + 250V								
for 5 seconds. Charging	500V to <u><</u> 1kV	2.5 times		1.5 ti	mes	2.5 times	1.5 times								
current limited to 50mA	>1kV to ≤1.2kV		N/A	1.25 t	imes		1.25 times								
maximum.	>1.2kV			1.2 ti	mes		1.2 times								
Cl:	Chip	55/125/56	55/125/56	55/12	5/56	-		-							
Climatic category (IEC)	Dipped	-	-	-	55/125/21	-		•							
	Discoidal	-	-	-	55/125/56	-									
Ageing characteristic (Typical)					Zero										
Approvals	Syfer Chip	-	-	-	QC-32100	-	-								

Dielectric characteristics

Class II Dielectrics

Capacitors of this type have a dielectric constant range of 1000-4000 and also have a non-linear temperature characteristic which exhibits a dielectric constant variation of less than $\pm 15\%$ (2R1) from its room temperature value, over the specified temperature range. Generally used for by-passing (decoupling), coupling, filtering, frequency discrimination, DC blocking and voltage transient suppression with greater volumetric efficiency than Class I units, whilst maintaining stability within defined limits.

Capacitance and dissipation factor are affected by:-

- a) Time (Ageing)
- b) Voltage (AC or DC)
- c) Frequency

		Clas	ss II Dielect	rics								
X5R	X7R			X8R		ss II nperature						
Stable		Stable		Stable	Sta	ble						
-	2C1	2R1	2X1	-	-	-	IECQ-CECC	Dielectric				
X5R	-	X7R	-	X8R	-	-	EIA	classifications				
-	BZ	-	BX	-	-	-	MIL					
-	-	-	-	-	-	-	DLI					
BW	-	В	Х	S	G	E, RE	Novacap	Ordering code				
Р	R X B				-	Χ	Syfer	Ordering code				
-	-	X	-	-	-	-	Voltronics					
-55°C to +85°C		-55°C to +125°C		-55°C to +150°C	-55°C to +160°C	-55°C to +200°C		Rated temperature range				
±15%	±15%	±15% ±15% ±1		±15%	+15 -40% +15 -65%		No DC voltage applied	Maximum capacitance change over				
-	+15 -45%	-	+15 -25%	-	-	-	Rated DC voltage applied	temperature range				
≤ 0.025 Typical*		>25V <0.025 <25V <0.035		≤0.025	<u>≤</u> 0.	025		Tangent of loss angle (tan δ)				
	$100G\Omega$ or $1000s$ (whichever is the least)											
		Capacitance Tolerance										
		2.5 times			2.5 t	imes	<u>≤</u> 200V	Dielectric				
2.5 times	Ra	ated voltage + 250	0V	25#	Rated volta	age + 250V	>200V to <500V	strength Voltage applied for 5 seconds.				
2.5 unies		1.5 times		2.5 times	1.5 t	imes	500V to <1kV	Charging current limited to 50mA				
		1.2 times			1.2 t	imes	≥1kV	maximum.				
55/85/56		55/125/56		55/150/56		Chip	Climatic					
-		55/125/21		-		Dipped	Climatic category (IEC)					
-		55/125/56		-		-	Discoidal					
5% Typical			Ageing characteristic (Typical)									
-	QC-32100	-	-	-	QC-32100	-	Syfer Chip	Approvals				

 $[\]ensuremath{^{*}}$ Refer to page 34 for details of Dissipation Factor.

Dielectric termination combinations

		Palladium Silver	Palladium Silver	Nickel Barrier (100% matte tin plating). Lead free	Nickel Barrier 90/10% tin/lead	Nickel Barrier Gold flash	FlexiCap Tm with Nickel Barrier 100% tin	FlexiCap Tm with Nickel Barrier 90/10% tin/lead	FlexiCap™ with Copper Barrier 100% tin	FlexiCap™ Ag Layer, 400-u-in Cu barrier 200-u-in Sn Plate	FlexiCap [™] with Copper Barrier 90/10% tin/lead	Copper Barrier 100% tin	Ag Layer, 400-500u-in Cu barrier, 200-u-in 90/10 Sn Plate	Copper Barrier 90/10% tin/lead	Solderable Silver	Solderable Palladium Silver
			RoHS	RoHS		RoHS	RoHS		RoHS			RoHS			RoHS	RoHS
Recommended for Solder Attachment				•	•		•	•	•	•	•	•	•	•	•	•
Recommended for Conductive Epoxy Attachment		•	•			•										
	DLI	-	-	Z	U	s	-	-	-	-	-	-	-	-	-	-
Termination	Novacap	Р	PR	N	Y	NG	С	D	_	_	_	В	_	E	s	K
ordering code:	Syfer	-	F	J	A	_	Y	н	3	_	5	2	_	4		_
Dialactuia					^		•		J		•			-		
Dielectric	Code DLI - UL					•										
COG - Hi Q/Low ESR	Syfer - Q, U			•	•											
COG - Hi Q/Low ESR BME	Syfer - H			•												
COO TH Q/LOW LOCK DITE	Novacap - N/RN	•	•		•	•	•	•							•	•
COG/NPO	Syfer - A			•			•									
	Syfer - C, F		•		•		•	•								
COG/NPO - BME	Syfer - G, K			•	_											
,	Novacap - M	•	•									•		•		•
COG/NPO -	Syfer - C, Q								•		•	•		•		
Non-Mag	Voltronics - Q		•							•		•	•			
	Syfer - P		•	•	•		•	•								
X5R	Novacap - BW			•	•	•										
	Novacap - B/RB	•	•	•	•	•	•	•							•	•
X7R	Syfer - E						•									
	Syfer - X, D		•	•	•		•	•								
	Novacap - BB			•	•	•										
X7R - BME	Syfer - J			•			•									
	Syfer - S						•									
вх	Novacap - X	•	•	•	•	•	•	•							•	•
DA	Syfer - B		•	•	•		•	•								
R2D (Pulse Energy)	Novacap - R	•	•													•
BZ	Syfer - R		•	•	•		•	•								
X7R - Non-Mag	Novacap - C	•	•									•		•		•
	Syfer - X								•		•					
	Voltronics - X		•						•	•			•			
X8R	Novacap - S	•	•	•	•		•	•							•	•
	Syfer - N						•									
000 (ND0 (4 0000)	Syfer - T						•									
COG/NPO (160°C)	Novacap - F	•	•	•	•		•	•							•	•
COG/NPO (200°C)	Novacap - D														•	•
COG/NPO (200°C)	Novacap - RD			•												
Class II (1600C)	Syfer - G Novacap - G	•	•	•			•	•								
Class II (160°C)	Novacap - G				•										•	•
	TOTALCOD L															